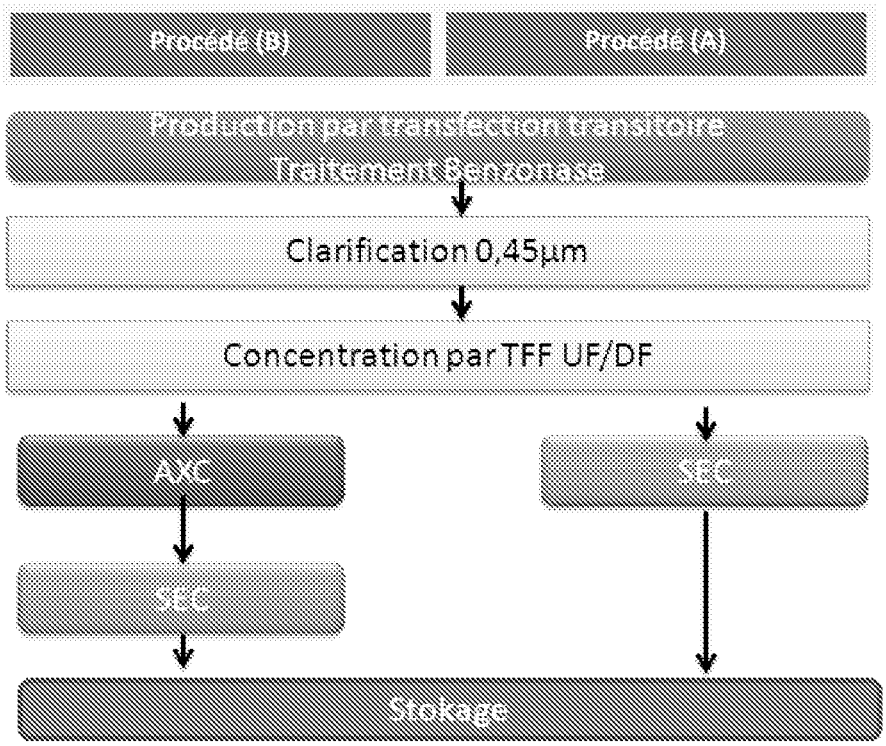


Figure 1

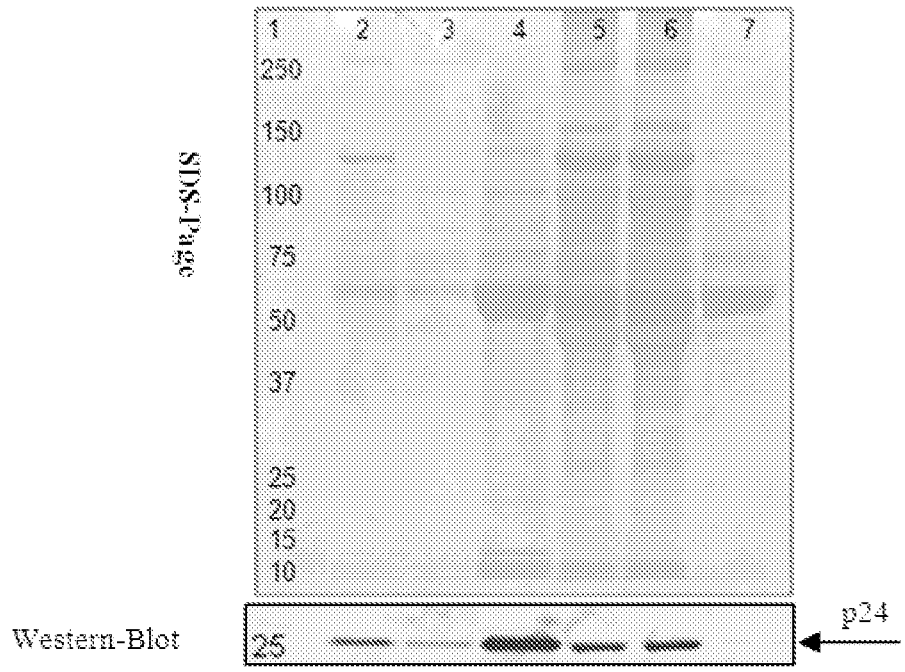


Figure 2

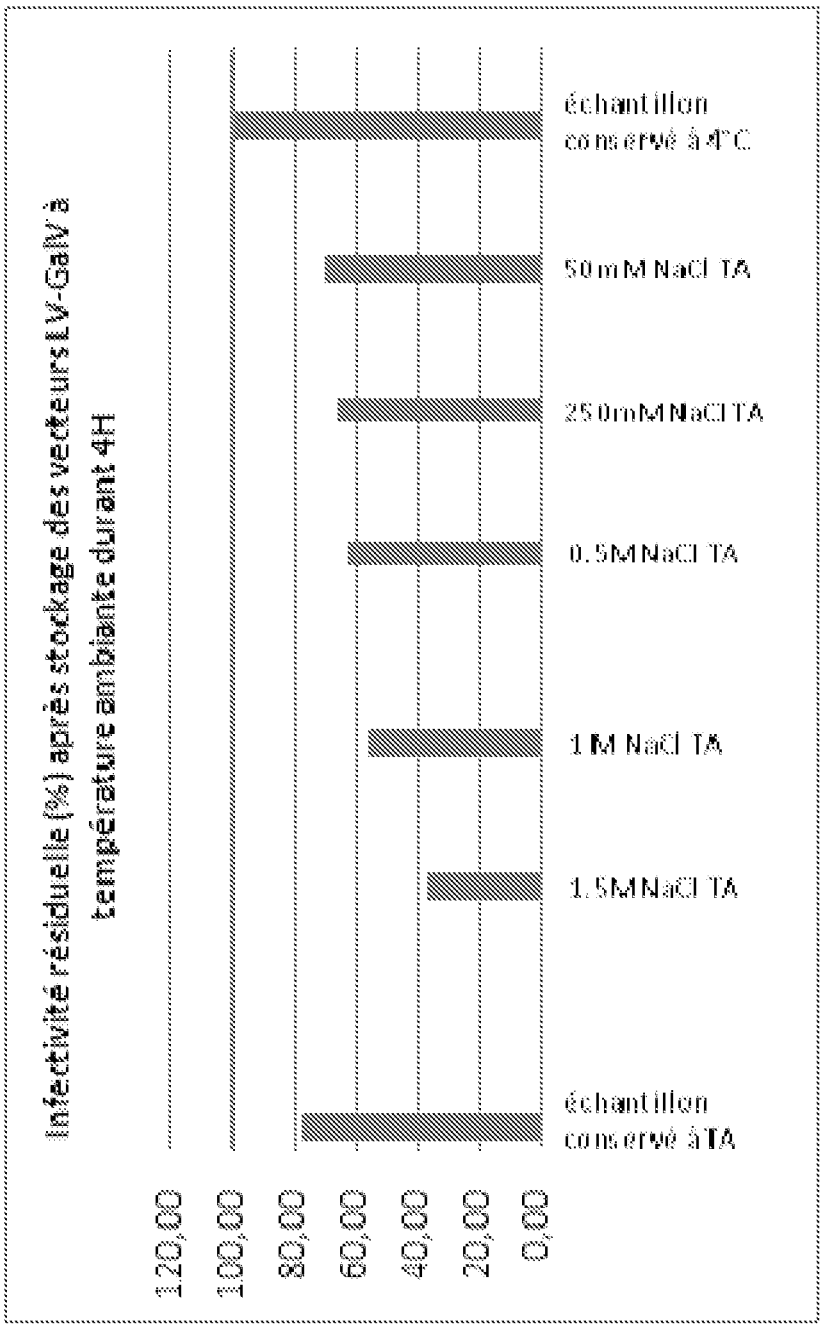

Infectivité résiduelle (%) après stockage des vecteurs LV-GaN à température ambiante durant 4H
échantillon conservé à 4°C
50 mM NaCl TA
250 mM NaCl TA
0.5M NaCl TA
1 M NaCl TA
1.5M NaCl TA
échantillon conservé à TA
120,00
100,00
80,00
60,00
40,00
20,00
0,00

Figure 3

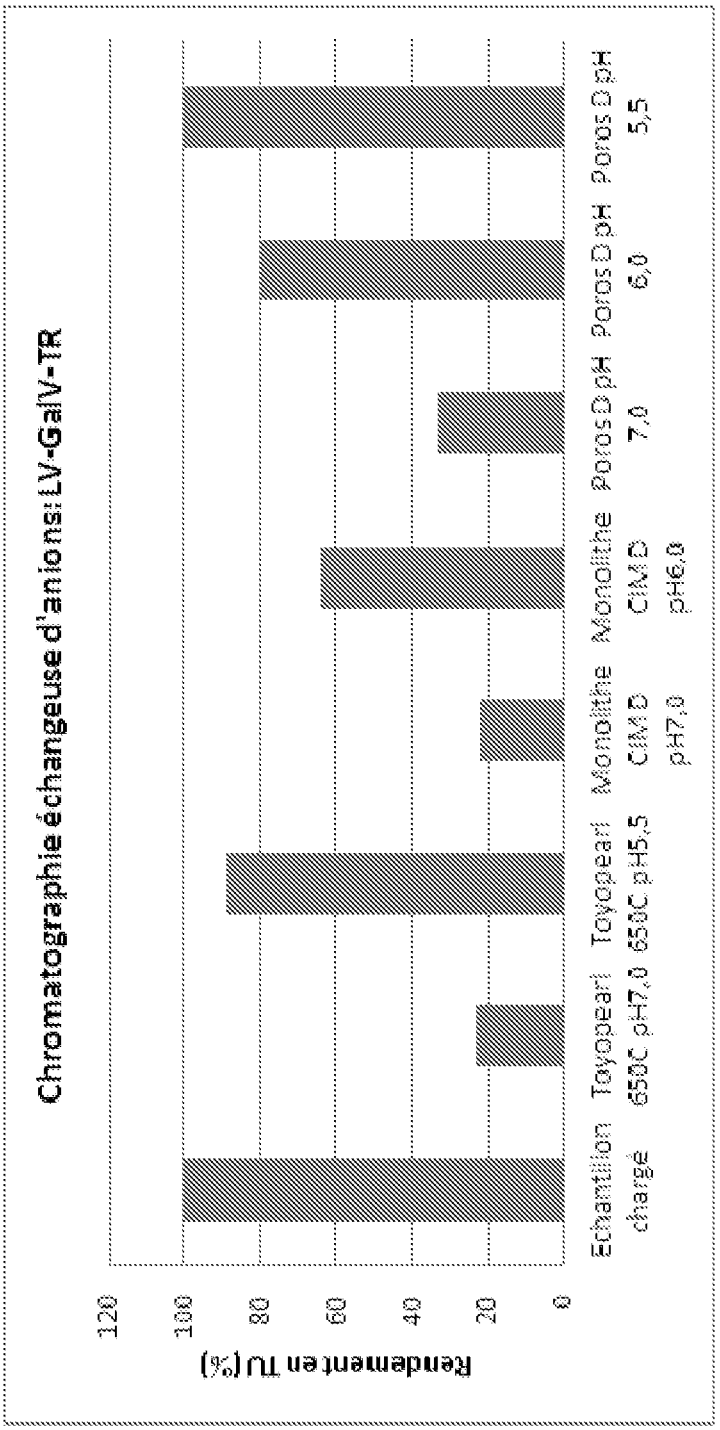

Chromatographie échangeuse d'anions: LV-GalV-TR
Rendement en TU (%)
120
100
80
60
40
20
0
Echantillon chargé
Toyopearl 650C pH7,0
Toyopearl 650C pH5,5
Monolithe CIM D pH7,0
Monolithe CIM D pH6,8
Poros D pH 7,0
Poros D pH 6,0
Poros D pH 5,5
Test des supports, conditions

Figure 4

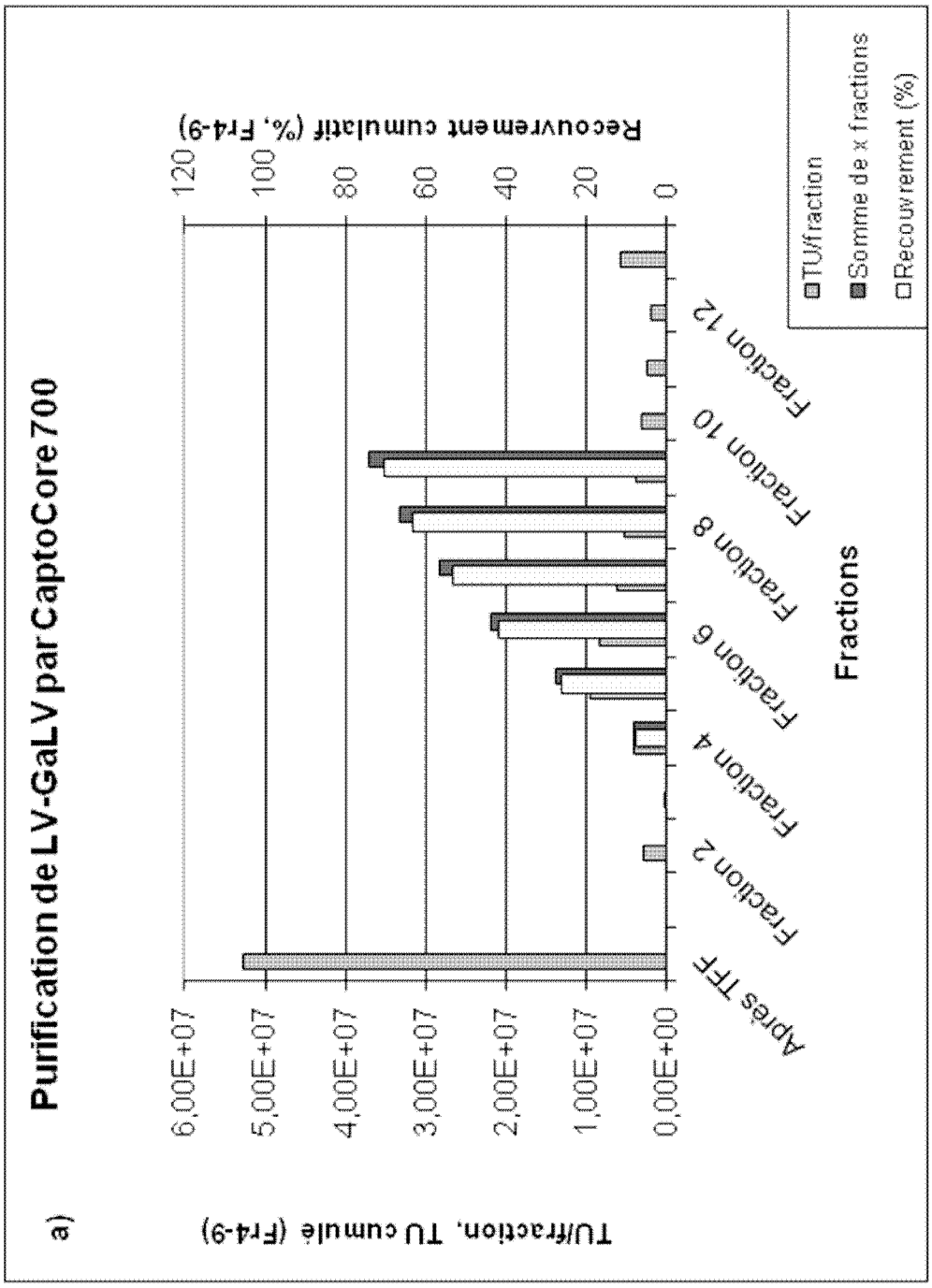

a)
Purification de LV-GaLV par CaptoCore 700
TU/fraction, TU cumulé (Fr4-9)
Recouvrement cumulatif (%, Fr4-9)
6,00E+07
5,00E+07
4,00E+07
3,00E+07
2,00E+07
1,00E+07
0,00E+00
120
100
80
60
40
20
0
Après TFF
Fraction 2
Fraction 4
Fraction 6
Fraction 8
Fraction 10
Fraction 12
Fractions
TU/fraction
Somme de x fractions
Recouvrement (%)

Figure 5

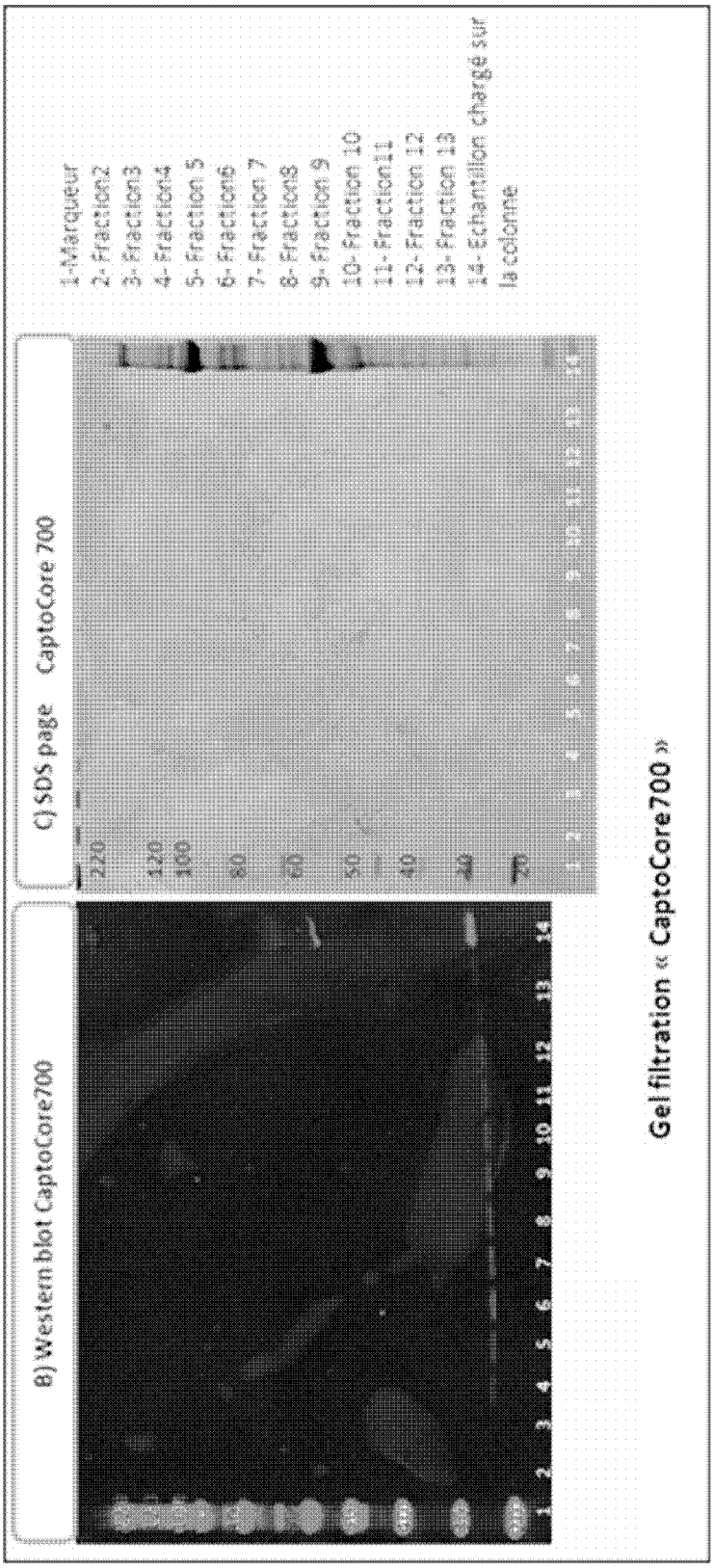


Figure 5 (suite)

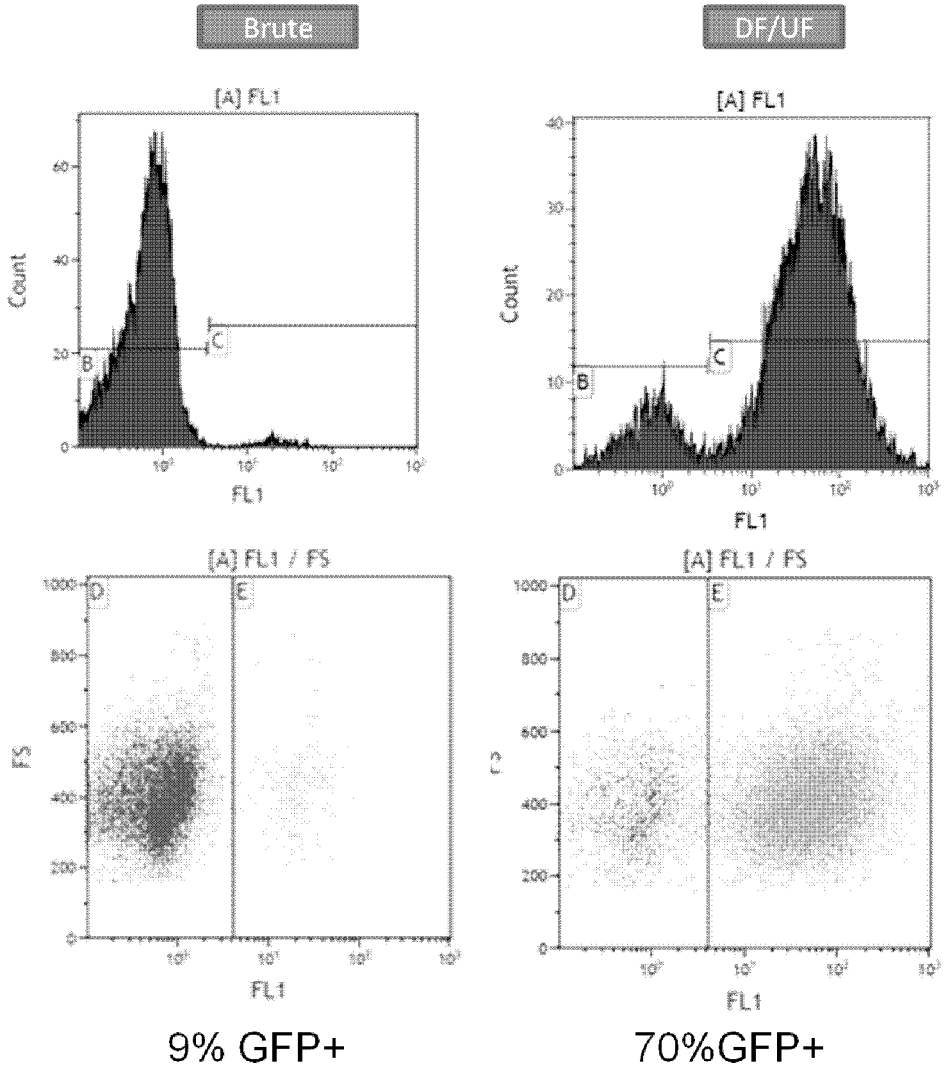


Figure 6